NSN 5962-01-113-2799

Memory Microcircuit - Page 1 of 1

Fiig: A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-113-2799
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Asynchronous and synchronous and bipolar and bistable and burn in and complementary outputs and hermetically sealed and high speed
and monolithic and positive edge triggered and positive outputs and w/clear and w/clock and w/preset and w/independent outputs and
w/totem pole output and 2-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
Dual 5 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
8.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level
output
Test Data Document:
93322-7000657 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli